## NSN 5961-01-216-5326

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View Online at https://aerobasegroup.com/nsn/5961-01-216-5326 **Inclosure Material:** Metal **Overall Length:** 8.327 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 150.00 milliamperes forward current, total rms absolute **Power Rating Per Characteristic:** 16.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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